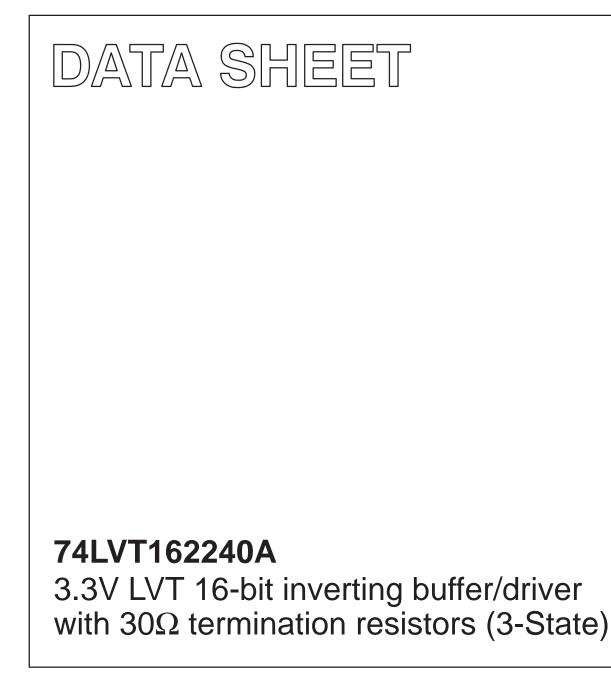
INTEGRATED CIRCUITS



Product specification Supersedes data of 1995 Aug 22 IC23 Data Handbook

1998 Feb 19



Philips Semiconductors

3.3V 16-bit inverting buffer/driver with 30Ω termination resistors (3-State)

74LVT162240A

FEATURES

- 16-bit bus interface
- 3-State buffers
- Output capability: +12mA/-12mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Outputs include series resistance of 30Ω making external termination resistors unnecessary
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model
- Same part as 74LVT16240A-1

QUICK REFERENCE DATA

DESCRIPTION

The 74LVT162240A is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

This device is an inverting 16-bit buffer that is ideal for driving bus lines. The device features four Output Enables $(1\overline{OE}, 2\overline{OE}, 3\overline{OE}, 4\overline{OE})$, each controlling four of the 3-State outputs.

The 74LVT162240A is designed with 30Ω series resistance in both the pull-up and pull-down output structures. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus receivers/transmitters.

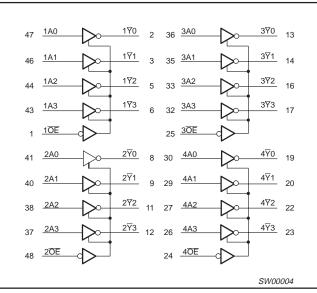
The 74LVT162240A is the same as the 74LVT16240A-1. The part number has been changed to reflect industry standards.

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	$C_L = 50 pF;$ $V_{CC} = 3.3 V$	2.6	ns
C _{IN}	Input capacitance nOE	$V_{I} = 0V \text{ or } 3.0V$	3	pF
C _{OUT}	Output capacitance	$V_{O} = 0V \text{ or } 3.0V$	9	pF
I _{CCZ}	Total supply current	Outputs disabled; $V_{CC} = 3.6V$	70	μΑ

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	–40°C to +85°C	74LVT162240A DL	VT162240A DL	SOT370-1
48-Pin Plastic TSSOP Type II	–40°C to +85°C	74LVT162240A DGG	VT162240A DGG	SOT362-1

LOGIC SYMBOL



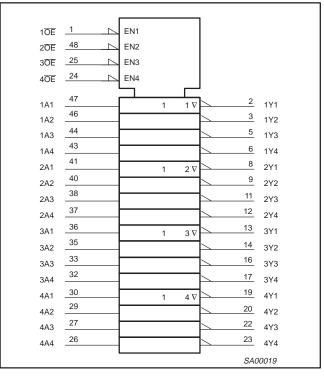
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
47, 46, 44, 43, 41, 40, 38, 37, 36, 35, 33, 32, 30, 29, 27, 26	1A0 - 1A3 2A0 - 2A3 3A0 - 3A3 4A0 - 4A3	Data inputs
2, 3, 5, 6, 8, 9, 11, 12, 13, 14, 16, 17, 19, 20, 22, 23	1\overline{TO} - 1\overline{T3} 2\overline{T0} - 2\overline{T3} 3\overline{T0} - 3\overline{T3} 4\overline{T0} - 4\overline{T3}	Data outputs
1, 48 25, 24	1 <u>0E,</u> 2 <u>0E,</u> 30E, 40E	Output enables
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V _{CC}	Positive supply voltage

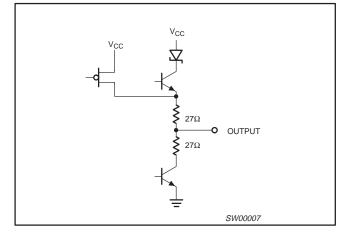
3.3V 16-bit inverting buffer/driver with 30Ω termination resistors (3-State)

74LVT162240A

LOGIC SYMBOL (IEEE/IEC)



SCHEMATIC OF EACH OUTPUT



PIN CONFIGURATION

		٦	
1 0E	1	48	2 0E
1∀0	2	47	1A0
171	3	46	1A1
GND	4	45	GND
172	5	44	1A2
1₹3	6	43	1A3
VCC	7	42	VCC
2 \ 0	8	41	2A0
270 2 <u>7</u> 1	9	40	2A1
GND	10	39	GND
272	11	38	2A2
2 <u>7</u> 3	12	37	2A3
3 <u>7</u> 0	13	36	3A0
3₹1	14	35	3A1
GND	15	34	GND
3₹2	16	33	3A2
3₹4	17	32	3A3
VCC	18	31	VCC
4 <u>₹</u> 0	19	30	4A0
4₹1	20	29	4A1
GND	21	28	GND
4 <u>7</u> 2	22	27	4A2
473	23	26	4A3
4 0E	24	25	3 0E
	SWOO	- 0006	

FUNCTION TABLE

INP	OUTPUTS	
nOE	nAx	n∀x
L	L	Н
L	Н	L
Н	Х	Z

H = High voltage level

L = Low voltage level

X = Don't care

Z = High Impedance "off" state

3.3V 16-bit inverting buffer/driver with 30Ω termination resistors (3-State)

74LVT162240A

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
		Output in Low state	128	
IOUT	DC output current	Output in High state	-64	mA
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the 1. device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction 2.

The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
STWBOL	FARAIMETER	MIN	MAX	UNIT
V _{CC}	DC supply voltage	2.7	3.6	V
VI	Input voltage	0	5.5	V
V _{IH}	High-level input voltage			V
V _{IL}	Input voltage		0.8	V
I _{ОН}	High-level output current		-12	mA
I _{OL}	Low-level output current		12	mA
Δt/Δv	Input transition rise or fall rate; Outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

3.3V 16-bit inverting buffer/driver with 30Ω termination resistors (3-State)

74LVT162240A

DC ELECTRICAL CHARACTERISTICS

				LIMITS			C UNIT
SYMBOL PARAMETER		TEST CONDITIONS		Temp = -40°C to +85°		+85°C	
				MIN	TYP ¹	MAX	
V _{IK}	Input clamp voltage	V _{CC} = 2.7V; I _{IK} = -18mA			-0.85	1.2	V
V _{OH}	High-level output voltage	V _{CC} = 3.0V; I _{OH} = -12mA		2.0			V
V _{OL}	Low-level output voltage	V _{CC} = 3.0V; I _{OL} = 12mA				0.8	V
		$V_{CC} = 3.6V; V_1 = V_{CC} \text{ or GND}$	Control pins		0.1	±1	
		$V_{CC} = 0 \text{ or } 3.6 \text{V}; \text{ V}_{\text{I}} = 5.5 \text{V}$			0.4	10	1
łı	Input leakage current	$V_{CC} = 3.6V; V_{I} = V_{CC}$			0.1	1	μA
		$V_{CC} = 3.6V; V_{I} = 0$	Data pins ⁴		-0.4	-5	
I _{OFF}	Output off current	$V_{CC} = 0V; V_1 \text{ or } V_0 = 0 \text{ to } 4.5V$			0.1	±100	μA
		$V_{CC} = 3V; V_{I} = 0.8V$		75	135		μΑ
I _{HOLD}	Bus Hold current A outputs ⁶	$V_{CC} = 3V; V_1 = 2.0V$		-75	-135		
		$V_{CC} = 0V$ to 3.6V; $V_{CC} = 3.6V$		±500			
I_{EX}	Current into an output in the High state when $V_O > V_{CC}$	V _O = 5.5V; V _{CC} = 3.0V			50	125	μΑ
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = GND$ or V_{CC} OE/OE = Don't care			1	±100	μΑ
I _{OZH}	3-State output High current	V_{CC} = 3.6V; V_{O} = 3.0V; V_{I} = V_{IL} or V_{IH}	V_{CC} = 3.6V; V_O = 3.0V; V_I = V_{IL} or V_{IH}		0.5	5	μΑ
I _{OZL}	3-State output Low current	V_{CC} = 3.6V; V_{O} = 0.5V; V_{I} = V_{IL} or V_{IH}			0.5	-5	μA
I _{CCH}		$V_{CC} = 3.6V$; Outputs High, $V_I = GND$ or	V _{CC} , I _{O =} 0		0.07	0.12	
I _{CCL}	Quiescent supply current	V_{CC} = 3.6V; Outputs Low, V_I = GND or V_{CC} , I_O = 0			4.0	6	mA
I _{CCZ}	1	V_{CC} = 3.6V; Outputs Disabled; V_{I} = GNE		0.07	0.12	1	
ΔI_{CC}	Additional supply current per input pin ²	V_{CC} = 3V to 3.6V; One input at V_{CC} -0.6V Other inputs at V_{CC} or GND	/,		0.1	0.20	mA

NOTES:

1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^{\circ}C$. 2. This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND 3. This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From $V_{CC} = 1.2V$ to $V_{CC} = 3.3V \pm 0.3V$ a transition time of 100 μ sec is permitted. This parameter is valid for T_{amb} = 25°C only. 4. Unused pins at V_{CC} or GND.

5. I_{CCZ} is measured with outputs pulled to V_{CC} or GND.

6. This is the bus hold overdrive current required to force the input to the opposite logic state.

AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to +85°C.

			LIMITS				
SYMBOL	PARAMETER	WAVEFORM	V _{CC}	c = 3.3V ±0.	.3V	V _{CC} = 2.7V	UNIT
			MIN	TYP ¹	MAX	MAX	
t _{PLH} t _{PHL}	Propagation delay nAx to n∀x	1	0.5 0.5	2.6 2.6	4.2 4.2	5.0 5.0	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.0 1.0	3.3 3.0	5.5 5.0	6.5 5.5	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	2	1.0 1.0	3.5 3.2	5.0 4.5	5.5 4.5	ns

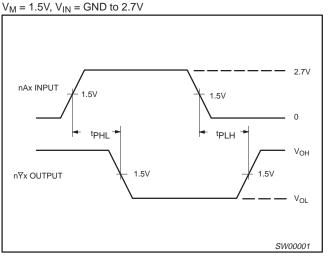
NOTE:

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

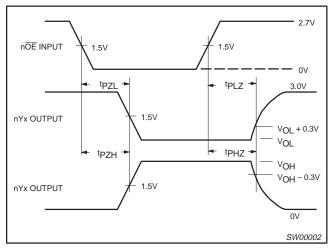
3.3V 16-bit inverting buffer/driver with 30Ω termination resistors (3-State)

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AC WAVEFORMS

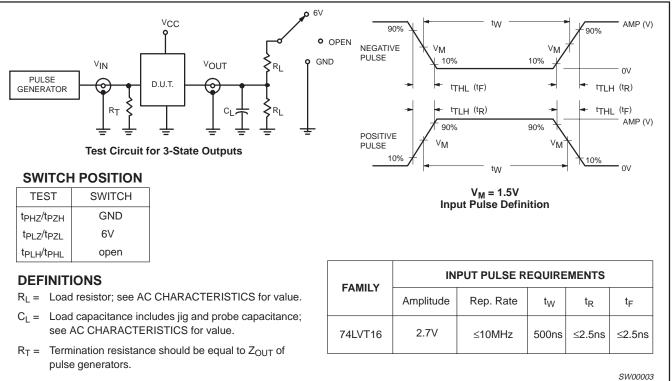






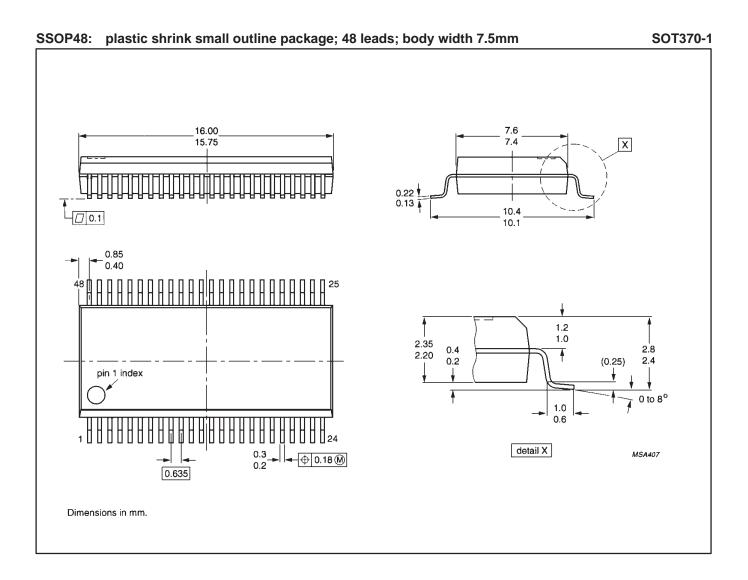


TEST CIRCUIT AND WAVEFORMS



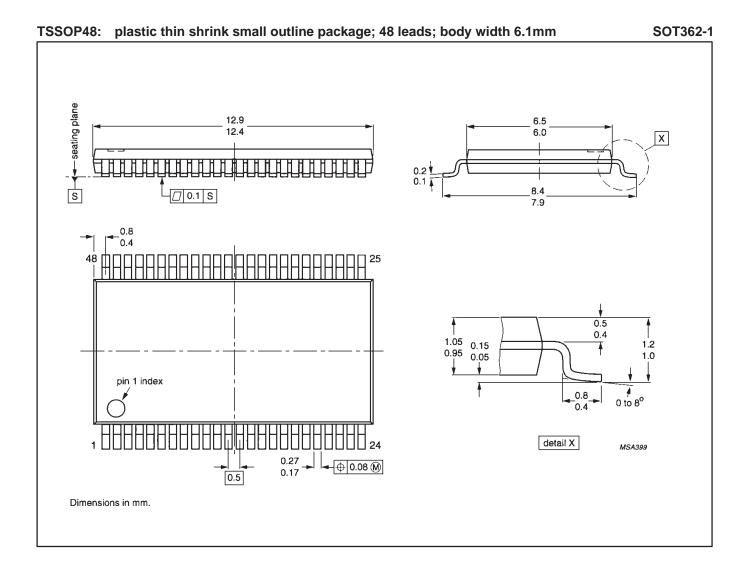
3.3V LVT 16-bit inverting buffer/driver with 30Ω termination resistors (3-State)

74LVT162240A



3.3V LVT 16-bit inverting buffer/driver with 30Ω termination resistors (3-State)

74LVT162240A



3.3V LVT 16-bit inverting buffer/driver with 30Ω termination resistors (3-State)

74LVT162240A

NOTES

3.3V LVT 16-bit inverting buffer/driver with 30Ω termination resistors (3-State)

74LVT162240A

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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